

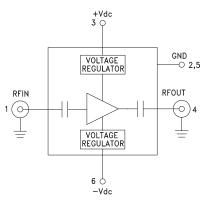


### **Typical Applications**

The HMC-C020 Wideband PA is ideal for:

- Microwave Radio & VSAT
- Military & Space
- Test & Lab Instrumentation

### **Functional Diagram**



## WIDEBAND POWER AMPLIFIER MODULE, 17 - 24 GHz

#### **Features**

Gain: 22 dB

P1dB Output Power: +24 dBm

Noise Figure: 3.5 dB Spurious-Free Operation

Regulated Supply and Bias Sequencing

Hermetically Sealed Module

Field Replaceable 2.92mm connectors
-55 °C to +85 °C Operating Temperature

# General Description

The HMC-C020 is a GaAs MMIC PHEMT Power Amplifier in a miniature, hermetic module with replaceable 2.92mm connectors which operates between 17 and 24 GHz. The amplifier provides 22 dB of gain, 3.5 dB noise figure, +33 dBm output IP3 and up to +24 dBm of output power at 1 dB gain compression. The wideband amplifier I/Os are internally matched to 50 Ohms and are DC blocked making the HMC-C020 ideal for EW, ECM RADAR and test equipment applications. Integrated voltage regulators allow for flexible biasing of both the negative and positive supply pins, while internal bias sequencing circuitry assures robust operation.

## Electrical Specifications, $T_A = +25^{\circ}$ C, +Vdc = +8V to +15V, -Vdc = -4V to $-10V^*$

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		17 - 20			20 - 24		GHz
Gain	19	22	24	19	22	24	dB
Gain Flatness		±1.0			±0.5		dB
Gain Variation Over Temperature		-0.03	-0.04		-0.03	-0.04	dB/ °C
Noise Figure		3.5	5.5		4.5	6.5	dB
Input Return Loss		7			7		dB
Output Return Loss		10			10		dB
Output Power for 1 dB Compression (P1dB)	20	23		20	24		dBm
Saturated Output Power (Psat)		25			26		dBm
Output Third Order Intercept (IP3)		33			33		dBm
Positive Supply Current (+IDC)		250			250		mA
Negative Supply Current (-IDC)		5.2			5.2		mA

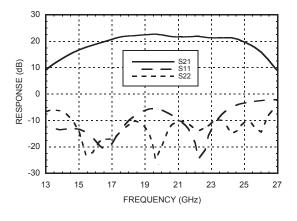
<sup>\*</sup> Data recorded at +Vdc = +12V and - Vdc = -5V



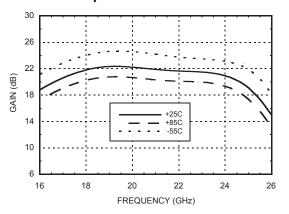


## WIDEBAND POWER AMPLIFIER MODULE, 17 - 24 GHz

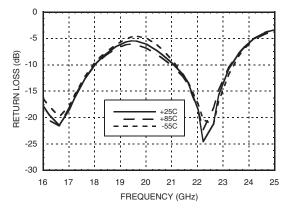
#### Gain & Return Loss



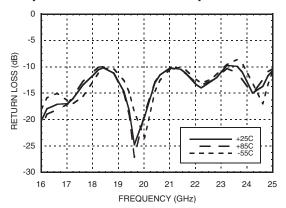
### Gain vs. Temperature



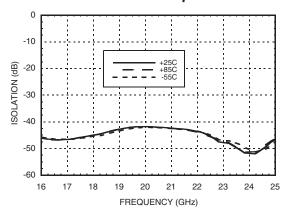
## Input Return Loss vs. Temperature



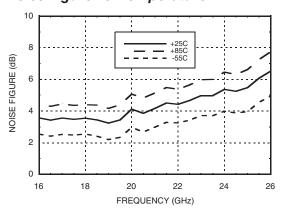
### Output Return Loss vs. Temperature



### Reverse Isolation vs. Temperature



### Noise Figure vs. Temperature

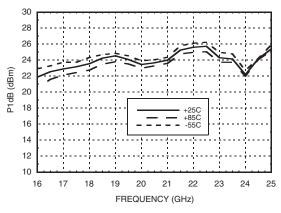




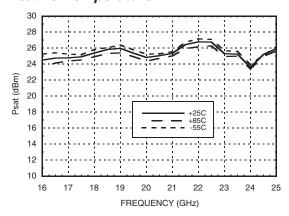


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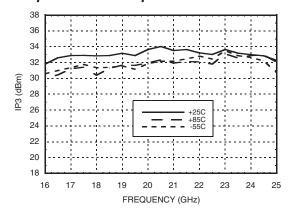
### P1dB vs. Temperature



### Psat vs. Temperature



### Output IP3 vs. Temperature



### **Absolute Maximum Ratings**

Positive Bias Supply Voltage (+Vdc)	+17V Max	
Negative Bias Supply (-Vdc)	-16V Min.	
RF Input Power (RFIN)	+20 dBm	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-55 to +85 °C	







## WIDEBAND POWER AMPLIFIER MODULE, 17 - 24 GHz

### **Pin Descriptions**

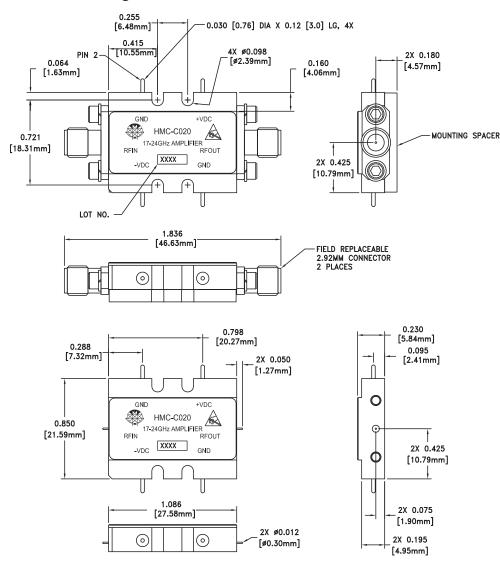
Pin Number	Function	Description	Interface Schematic	
1	RFIN	RF input connector, 2.92mm female, field replaceable. This pin is AC coupled and matched to 50 Ohms.	RFIN ○──   ├──	
2, 5	GND	Power supply ground.	→ GND =	
3	+Vdc	Positive power supply voltage for the amplifier.	+Vdc O VOLTAGE REGULATOR -	
4	RFOUT	RF output connector, 2.92mm female. This pin is AC coupled and matched to 50 Ohms.	—   —○ RFOUT	
6	-Vdc	Negative power supply voltage for the amplifier	-VdcO VOLTAGE REGULATOR	





## WIDEBAND POWER AMPLIFIER MODULE, 17 - 24 GHz

### **Outline Drawing**



VIEW SHOWN WITH CONNECTORS REMOVED

## Package Information

Package Type	C-10
Package Weight [1]	18.7 gms <sup>[2]</sup>
Spacer Weight	3.3 gms <sup>[2]</sup>

[1] Includes the connectors

[2] ±1 gms Tolerance

#### NOTES:

- 1. PACKAGE, LEADS, COVER MATERIAL: KOVAR $^{\text{TM}}$
- 2. FINISH: GOLD PLATE OVER NICKEL PLATE
- 3. ALL DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. TOLERANCES:
  - 4.1 .XX = ±0.02
  - $4.2.XXX = \pm 0.010$
- 5. FIELD REPLACEABLE 2.92mm CONNECTORS TENSOLITE 231CCSF OR EQUIVALENT



1

**AMPLIFIERS** 



**ANALOG**DEVICES

**Notes:** 

WIDEBAND POWER AMPLIFIER MODULE, 17 - 24 GHz